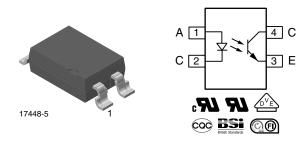


Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}

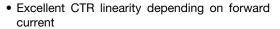


DESCRIPTION

The SFH6156 features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES





- Isolation test voltage, 5300 V_{RMS}
- · Fast switching times
- · Low CTR degradation
- Low coupling capacitance
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

APPLICATIONS

- Switchmode power supply
- Telecom
- Battery powered equipment

AGENCY APPROVALS

The safety application model number covering all products in this datasheet is SFH615A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- cUL tested to CSA 22.2 bulletin 5A
- BSI IEC 60950, IEC 60065
- FIMKO EN6005, EN60950-1
- CQC G8898-2011

ORDERING INFORMATION	N						
S F H 6 1 PART NUMBER		# X 0 0 CTR PACKAGE OP	TION TAPE AND REEL	SMD-4 > 8 mm			
AGENCY CERTIFIED/PACKAGE		CTF	R (%)				
AGENOT GENTILES/TAGRAGE	10 mA						
UL, cUL, BSI, FIMKO, CQC	40 to 80	63 to 125	100 to 200	160 to 320			
CMD 4 100 mill mitals	SFH6156-1	SFH6156-2	SFH6156-3	SFH6156-4			
SMD-4, 100 mil, pitch	SFH6156-1T	SFH6156-2T	SFH6156-3T	SFH6156-4T			
VDE, UL, cUL, BSI, FIMKO, CQC	40 to 80	63 to 125	100 to 200	160 to 320			
	SFH6156-1X001	SFH6156-2X001	SFH6156-3X001	-			
SMD-4, 100 mil, pitch	SFH6156-1X001T	SFH6156-2X001T	SFH6156-3X001T	SFH6156-4X001T			
	-	-	SFH6156-3X001T1	-			



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V_R	6	V			
DC forward current		I _F	60	mA			
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	А			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		I _C	50	mA			
Collector current	t _p ≤ 1 ms	I _C	100	mA			
COUPLER							
Storage temperature range		T _{stg}	-55 to +150	°C			
Ambient temperature range		T _{amb}	-55 to +100	°C			
Soldering temperature (1)	max. 10 s	T _{sld}	260	°C			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD)

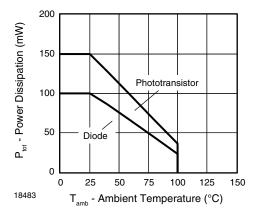


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



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THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P _{diss}	100	mW
Output power dissipation	P _{diss}	150	mW
Maximum LED junction temperature	T _{jmax.}	125	°C
Maximum output die junction temperature	T _{jmax.}	125	°C
Thermal resistance, junction emitter to board	θ_{EB}	173	°C/W
Thermal resistance, junction emitter to case	$\theta_{\sf EC}$	149	°C/W
Thermal resistance, junction detector to board	θ_{DB}	111	°C/W
Thermal resistance, junction detector to case	θ_{DC}	127	°C/W
Thermal resistance, junction emitter to junction detector	θ_{ED}	95	°C/W
Thermal resistance, board to ambient (1)	θ_{BA}	195	°C/W
Thermal resistance, case to ambient (1)	θ_{CA}	3573	°C/W

Notes

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
 temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
 PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal
 characteristics of optocouplers application note
- (1) For 2 layer FR4 board (4" x 3" x 0.062")

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		V_{F}	-	1.25	1.65	V
Reverse current	$V_R = 6 V$		I _R	-	0.01	10	μΑ
Capacitance	$V_R = 0 V$, $f = 1 MHz$		Co	-	13	-	pF
OUTPUT	OUTPUT						
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$		C _{CE}	-	5.2	-	pF
	V _{CE} = 10 V	SFH6156-1	I _{CEO}	-	2	50	nA
Collector omitter leakage augrent		SFH6156-2	I _{CEO}	-	2	50	nA
Collector emitter leakage current		SFH6156-3	I _{CEO}	-	5	100	nA
		SFH6156-4	I _{CEO}	-	5	100	nA
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V _{CEsat}	-	0.25	0.4	V
Coupling capacitance			C _C	-	0.4	-	pF

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements



CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		SFH6156-1	CTR	40	ı	80	%	
	I _F = 10 mA, V _{CE} = 5 V	SFH6156-2	CTR	63	ı	125	%	
	IF = 10 IIIA, VCE = 3 V	SFH6156-3	CTR	100	-	200	%	
I _C /I _F		SFH6156-4	CTR	160	-	320	%	
IC/IF		SFH6156-1	CTR	13	30	-	%	
	1 - 1 m	SFH6156-2	CTR	22	45	-	%	
	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH6156-3	CTR	34	70	-	%	
		SFH6156-4	CTR	56	90	-	%	

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Turn-on time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t _{on}	-	3	-	μs
Rise time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t _r	-	2	-	μs
Turn-off time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t _{off}	-	2.3	-	μs
Fall time	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		t _f	-	2	-	μs
Cut-off frequency	I_F = 10 mA, V_{CC} = 5 V, R_L = 75 Ω		f _{CO}	-	250	-	kHz
SATURATED							
	I _F = 20 mA	SFH6156-1	t _{on}	-	3	-	μs
T	I _F = 10 mA	SFH6156-2	t _{on}	-	4.2	-	μs
Turn-on time		SFH6156-3	t _{on}	-	4.2	-	μs
	I _F = 5 mA	SFH6156-4	t _{on}	-	6	-	μs
	I _F = 20 mA	SFH6156-1	t _r	-	2	-	μs
D'a a l'an a		SFH6156-2	t _r	-	3	-	μs
Rise time	I _F = 10 mA	SFH6156-3	t _r	-	3	-	μs
	I _F = 5 mA	SFH6156-4	t _r	-	4	-	μs
	I _F = 20 mA	SFH6156-1	t _{off}	-	18	-	μs
T 2###	1 10 1	SFH6156-2	t _{off}	-	23	-	μs
Turn-off time	I _F = 10 mA	SFH6156-3	t _{off}	-	23	-	μs
	I _F = 5 mA	SFH6156-4	t _{off}	-	25	-	μs
	I _F = 20 mA	SFH6156-1	t _f	-	11	-	μs
E-U.C.	I _F = 10 mA	SFH6156-2	t _f	-	14	-	μs
Fall time		SFH6156-3	t _f	-	14	-	μs
	I _F = 5 mA	SFH6156-4	t _f	-	15	-	μs

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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification	According to IEC 68 part 1		55/100/21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	10 000	V			
Maximum repetitive peak isolation voltage		V_{IORM}	890	V			
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω			
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Output safety power		P _{SO}	400	mW			
Input safety current		I _{SI}	275	mA			
Input safety temperature		T _{SI}	175	°C			
Creepage distance			≥ 7	mm			
Clearance distance			≥7	mm			
Insulation thickness		DTI	≥ 0.4	mm			

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

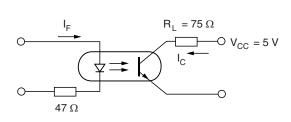
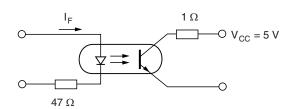


Fig. 2 - Linear Operation (without saturation)

isfh615a_01

Fig. 4 - Current Transfer Ratio (typ.) vs. Temperature



isfh615a_02

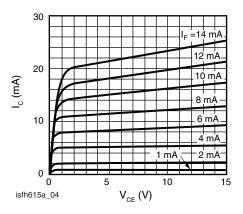


Fig. 3 - Switching Operation (with saturation)

Fig. 5 - Output Characteristics (typ.) Collector Current vs.

Collector Emitter Voltage

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits



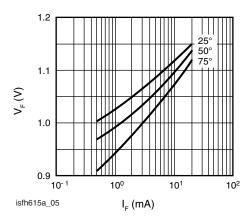


Fig. 6 - Diode Forward Voltage (typ.) vs. Forward Current

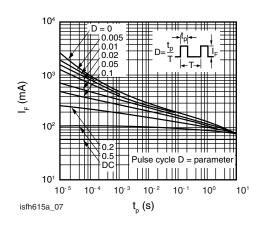


Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

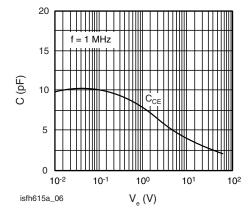
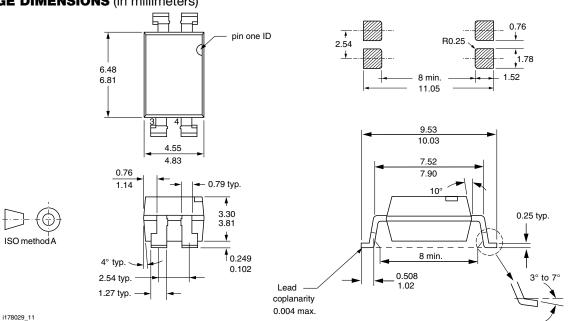


Fig. 7 - Transistor Capacitance (typ.) vs. Collector Emitter Voltage

PACKAGE DIMENSIONS (in millimeters)



Rev. 2.8, 21-Apr-17 6 Document Number: 83671



PACKAGE MARKING (example of SFH6156-2X001T)



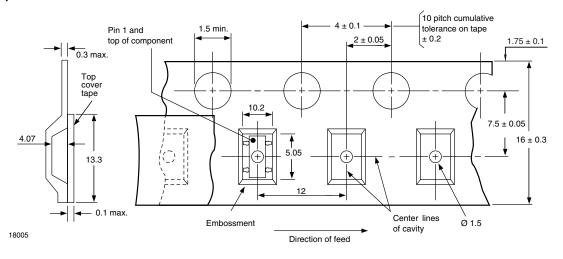
Notes

- · VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

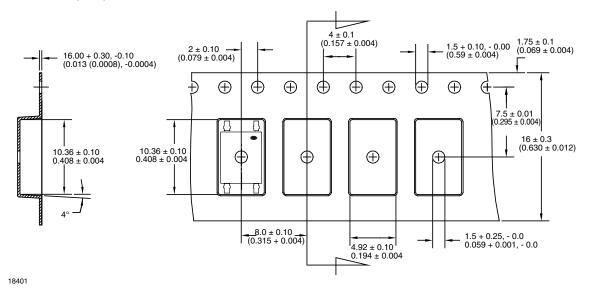
TAPE AND REEL PACKAGING (in millimeters)

The tape is 16 mm and is wound on a 33 cm reel. There are 1000 parts per reel. Taped and reeled 4 pin optocouplers conform to EIA-481-2 and IEC60286-3.

SMD-4 ("T")



SMD-4, 90° Rotation ("T1")





SOLDER PROFILES

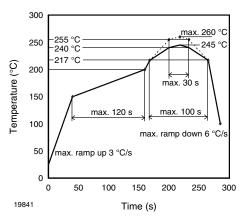


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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